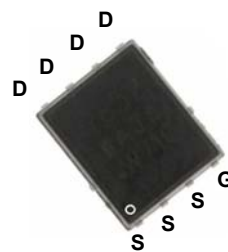
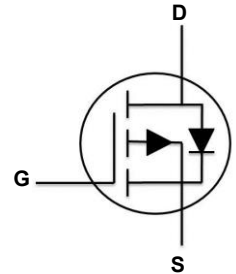


Main Product Characteristics

BV_{DSS}	-30V
$R_{DS(ON)}$	8.6mΩ @-10V (Typ)
	11.8mΩ @-4.5V (Typ)
I_D	-64A



PPAK5x6



Schematic Diagram

Features and Benefits

- Advanced MOSFET process technology
- Ideal for high efficiency switched mode power supplies
- Low on-resistance with low gate charge
- Fast switching and reverse body recovery



Description

The GSFP0365 utilizes the latest techniques to achieve high cell density and low on-resistance. These features make this device extremely efficient and reliable for use in high efficiency switch mode power supplies and a wide variety of other applications.

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Max.	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous ($T_C=25^{\circ}\text{C}$)	I_D	-64	A
Drain Current-Continuous ($T_C=70^{\circ}\text{C}$)		-51	
Drain Current-Pulsed ($T_C=25^{\circ}\text{C}$) ¹	I_{DM}	-224	A
Single Pulse Avalanche Energy ²	E_{AS}	101	mJ
Power Dissipation ($T_C=25^{\circ}\text{C}$)	P_D	56.8	W
Power Dissipation ($T_C=70^{\circ}\text{C}$)		45	
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.2	$^{\circ}\text{C/W}$
Operating Junction Temperature Range	T_J	-50 To +150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-50 To +150	$^{\circ}\text{C}$

Electrical Characteristics ($T_J=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
On / Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Zero Gate Voltage Drain Current (T _C =25°C)	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	μA
Zero Gate Voltage Drain Current (T _C =125°C)		V _{DS} =-24V, V _{GS} =0V	-	-	-100	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Static Drain-Source On-Resistance ³	R _{DS(ON)}	V _{GS} =-10V, I _D =-15A	-	8.6	12	mΩ
		V _{GS} =-4.5V, I _D =-10A	-	11.8	16	mΩ
Gate Threshold Voltage	V _{GS(th)}	V _{GS} =V _{DS} , I _D =-250uA	-1.0	-1.5	-2.5	V
Dynamic and Switching Characteristics						
Total Gate Charge	Q _g	V _{DS} =-15V, I _D =-15A V _{GS} =-10V	-	64.3	-	nC
Gate-Source Charge	Q _{gs}		-	6.9	-	
Gate-Drain Charge	Q _{gd}		-	16.5	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =-15V, R _G =6Ω V _{GS} =-10V, I _D =-1A	-	12	-	nS
Rise Time	t _r		-	41.8	-	
Turn-Off Delay Time	t _{d(off)}		-	80	-	
Fall Time	t _f		-	19.5	-	
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, F=1MHz	-	1360	-	pF
Output Capacitance	C _{oss}		-	373	-	
Reverse Transfer Capacitance	C _{rss}		-	137	-	
Drain-Source Diode Characteristics and Maximum Ratings						
Diode Forward Voltage ³	V _{SD}	V _{GS} =0V, I _{SD} =-15A, T _J =25°C	-	-0.85	-1.2	V

Note:

1. Repetitive rating: Pulsed width limited by maximum junction temperature.
2. $V_{GS}=10V, L=0.3\text{mH}, I_{AS}=26A, R_G=25\Omega$, starting $T_J=25^{\circ}\text{C}$.
3. Pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

Typical Electrical and Thermal Characteristic Curves

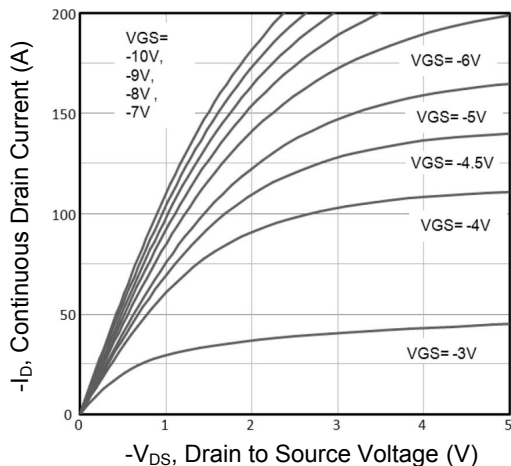


Figure 1. Typical Output Characteristics

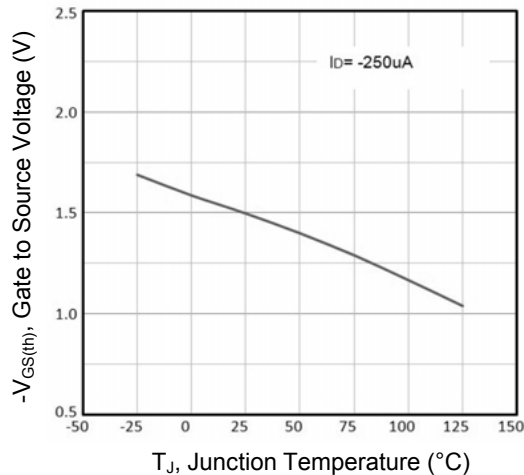


Figure 2. Normalized Threshold Voltage vs. T_J

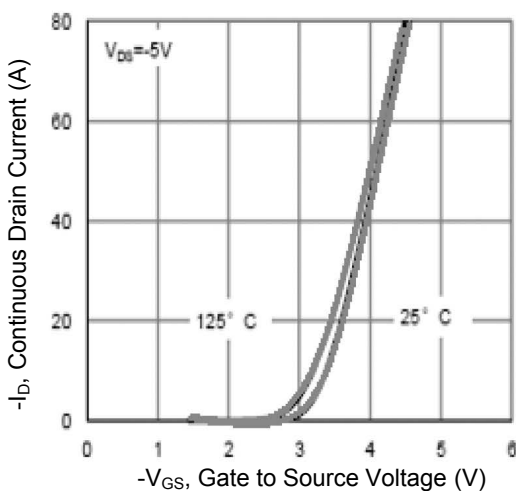


Figure 3. Typical Transfer Characteristics

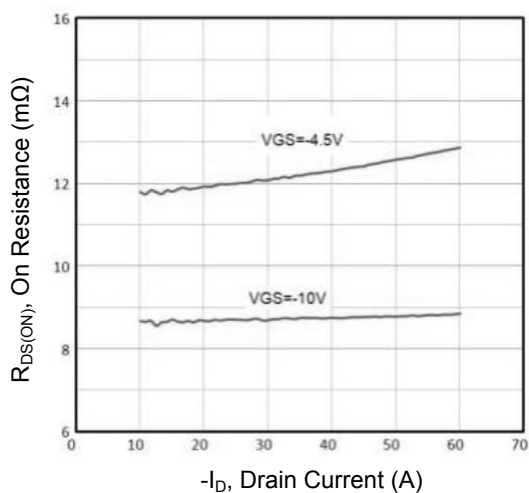


Figure 4. On Resistance vs. Drain Current

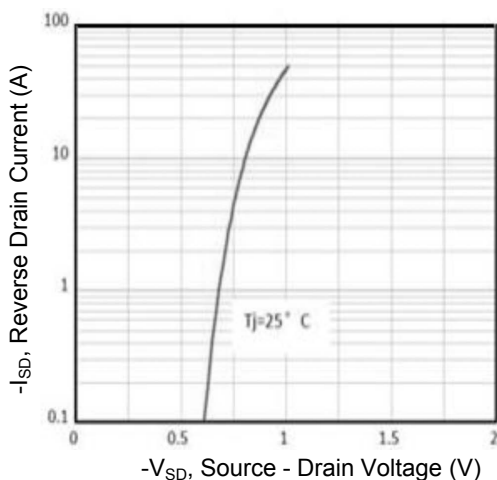


Figure 5. Typical Source - Drain Diode Forward Voltage

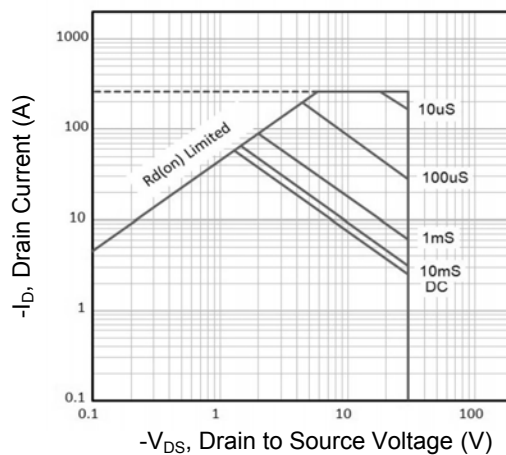


Figure 6. Maximum Safe Operating Area

Typical Electrical and Thermal Characteristic Curves

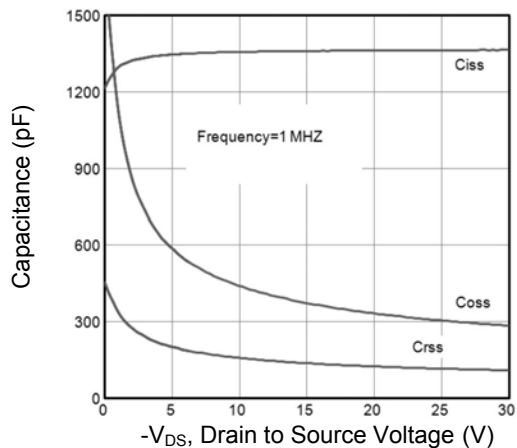


Figure 7. Capacitance Characteristics

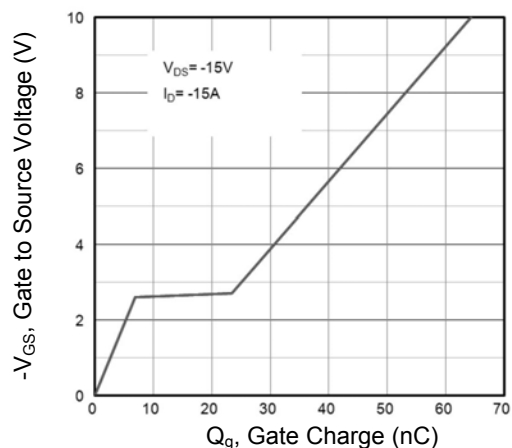


Figure 8. Gate Charge Characteristics

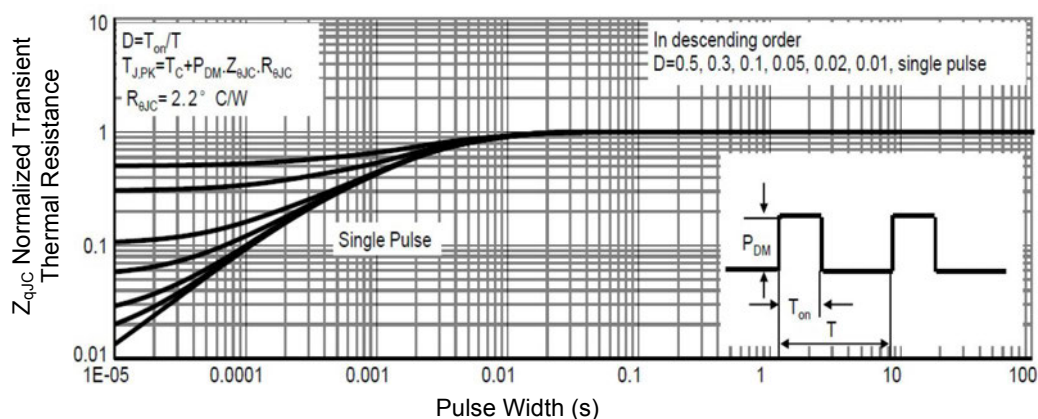


Figure 9. Normalized Maximum Transient Thermal Impedance

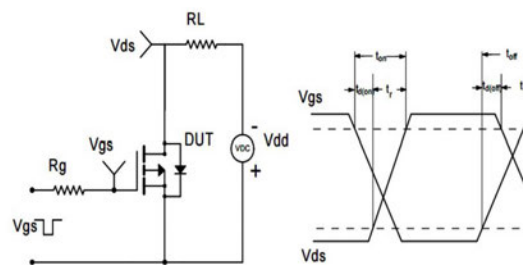


Figure 10. Switching Time Test Circuit and Waveforms

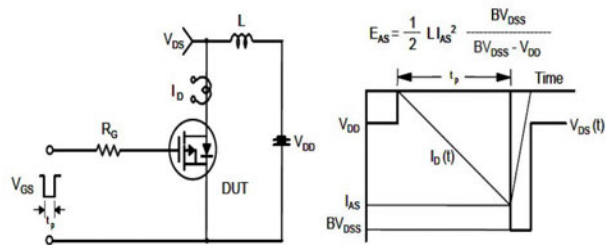
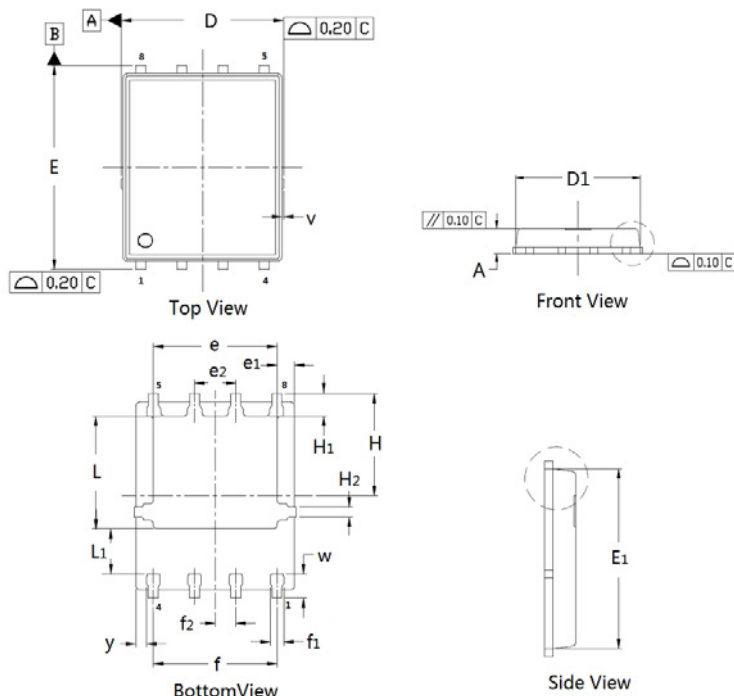


Figure 11. Unclamped Inductive Test Circuit and Waveforms

Package Outline Dimensions (PPAK5x6)



Symbol	Dimensions in Millimeters			Symbol	Dimensions in Millimeters		
	Min	Typ	Max		Min	Typ	Max
A	0.90	1.05	1.20	D	4.90	5.10	5.30
D ₁	4.80	4.89	5.00	E	6.00	6.15	6.30
E ₁	5.65	5.74	5.85	e	3.72	3.80	3.92
e ₁	-	0.54	-	e ₂	-	1.27	-
f	-	3.82	-	f ₁	0.31	0.37	0.51
f ₂	-	0.64	-	H	-	3.15	-
H ₁	0.59	0.63	0.79	H ₂	0.26	0.28	0.32
L	3.38	3.45	3.58	L ₁	-	1.39	-
v	-	0.13	-	w	0.64	0.68	0.84
y	-	0.34	-				

Order Information

Device	Package	Marking	Packaging	SPQ
GSFP0365	PPAK5x6	010P03	Tape & Reel	4,000 pcs / Reel